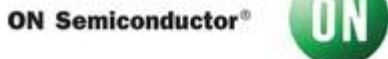
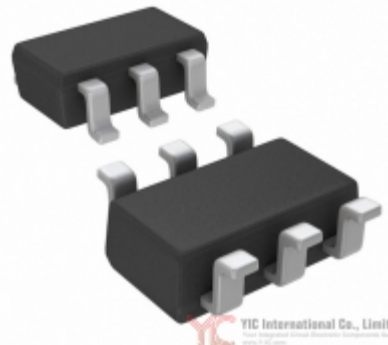



| | | |
|---|--------------------------------|--|
|  | NTGS3441PT1G | |
| | Hersteller-Teilenummer: | NTGS3441PT1G |
|  | Hersteller / Marke: | AMI Semiconductor / ON Semiconductor |
| | Teil der Beschreibung: | MOSFET P-CH 20V 1.8A 6-TSOP |
| | Datenblätter: |  NTGS3441PT1G.pdf |
| | RoHs Status: | Bleifrei / RoHS-konform |
| | Lagerzustand: | New original, 150856 pcs Stock Available. |
| | Liefern von: | Hong Kong |
| | Versandweg: | DHL/Fedex/TNT/UPS/EMS |
| Image may be representation. See specs for product details. | | |

Spezifikationen

| | |
|---|--|
| Teilenummer | NTGS3441PT1G |
| Hersteller | AMI Semiconductor / ON Semiconductor |
| Beschreibung | MOSFET P-CH 20V 1.8A 6-TSOP |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus | 150856 pcs Stock |
| Serie | - |
| Technologie | MOSFET (Metal Oxide) |
| Betriebstemperatur | -55°C ~ 150°C (TJ) |
| Befestigungsart | Surface Mount |
| Verpackung / Gehäuse | SOT-23-6 |
| Supplier Device-Gehäuse | 6-TSOP |
| Verlustleistung (max) | 510mW (Ta) |
| Typ FET | P-Channel |
| FET-Merkmal | - |
| Drain-Source-Spannung (Vdss) | 20V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 °C | 1.8A (Ta) |
| Rds On (Max) @ Id, Vgs | 110 mOhm @ 3A, 4.5V |
| VGS (th) (Max) @ Id | 1.6V @ 250µA |
| Gate Charge (Qg) (Max) @ Vgs | 6nC @ 4.5V |
| Eingabekapazität (Ciss) (Max) @ Vds | 345pF @ 15V |
| Verpackung | Tape & Reel (TR) |















































NTGS3441PT1G ist neu im Original, Suche NTGS3441PT1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTGS3441PT1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTGS3441PT1G: Info@Y-IC.com

Sie können auch interessiert sein:

| | | | |
|---|---|--|---|
|  NTGS3443BT1G AMI Semiconductor / ON Semiconductor MOSFET P-CH 20V 2.7A 6-TSOP |  NTGS3433T1 ONS NTGS3433T1 ONS |  NTGS3441LT1 ON NTGS3441LT1 ON |  NTGS3441T1G AMI Semiconductor / ON Semiconductor MOSFET P-CH 20V 1.65A 6-TSOP |
|  NTGS3442T1G ON NTGS3442T1G ON |  NTGS3441 ON NTGS3441 ON |  NTGS3441BT1G AMI Semiconductor / ON Semiconductor MOSFET P-CH 20V 2.2A 6-TSOP |  NTGS3433T1G AMI Semiconductor / ON Semiconductor MOSFET P-CH 12V 2.35A 6-TSOP |

heiße Teile

Mehr

| | | | | |
|---|--|--|---|--|
|  ADG701LBRTZ-REEL7 |  GJM0335C1E8R1CB01D |  GRM1885C1H222FA01D |  MIC5309-1.2YMTTR |  NTGD1100LT1G |
|  NTGD3122CT1G |  NTGD3133PT1G |  NTGD3147FT1G |  NTGD3148NT1G |  NTGD3149CT1G |
|  NTGD4161PT1G |  NTGD4161PT1G |  NTGD4167CT1G |  NTGD4167PT1G |  NTGD4169FT1G |
|  NTGS1135PT1G |  NTGS1N03LT1G |  NTGS1P02LT1G |  NTGS1P03LT1G |  NTGS3130N |
|  NTGS3130NT1G |  NTGS3136PT1G |  NTGS3433T1 |  NTGS3433T1G |  NTGS3441BT1G |
|  NTGS3441LT1 |  NTGS3441T1 |  NTGS3441T1G |  NTGS3441TI |  NTGS3442T1G |
|  NTGS3443BT1G |  NTGS3443T1 |  NTGS3443T1G |  NTGS3443T2G |  NTGS3445T1G |
|  NTGS3446T1 |  NTGS3446T1G |  NTGS3447PT1G |  NTGS3455T1G |  NTGS3A033PZT1G |
|  NTGS4111PT1G |  NTGS4111PT1G. |  NTGS4111PT2G |  NTGS4141NT1G |  NTGS5120PT1G |
|  NTHS5404T1 |  TDA6103Q |  TLE7238SL |  TPA5050RSAR |  VI-J21-IX |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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